Single-channel transm ission in gold one-atom contacts and chains

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We induce superconductivity by proximity e ect in thin layers of gold and study the number of conduction channels which contribute to the current in one-atom contacts and atom ic wires. The atom ic contacts and wires are fabricated with a Scanning Tunneling M icroscope. The set of transm ission probabilities of the conduction channels is obtained from the analysis of the I(V) characteristic curve which is highly non-linear due to multiple Andreev re ections. In agreement with theoretical calculations we nd that there is only one channel which is alm ost com pletely open. PACS numbers: 73.40.-c, 73.20.-r, 74.50.-h

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M uch e ort has been devoted in the last decade to the understanding of electron transport processes and mechanical properties of atom ic-sized point contacts and chains between metallic electrodes¹. Coherent electron transport in these nanostructures can be understood in the frame of the scattering form alism. The conductance G of these nanocontacts is given by the Landauer formula $G = G_0 \prod_{i=1}^{P} i_i$, where i are the transmission probabilities for each of N conductance channels and $G_0 = 2e^2 = h$ is the conductance quantum. For a given contact realization the conductance channels are in general neither com pletely open nor com pletely closed and the transparency i of each channel depends on the material form ing the contact^{2,3}, detailed atom ic arrangem ent and applied stress⁴. In this report we study the channeltransparency set f ig both in gold one-atom contacts and chains of single gold atom s^5 , for which theoretical models4,6,7,8,9 predict an almost completely open single channel, and therefore a conductance close to G_0 .

It is well established that conductance histograms (CH) show that the conductance of one-atom contacts of gold is close to G $_0^1$ but the values of $_1$ cannot be obtained from the only measurement of the total conductance. How ever, the marked non-linearity of the currentvoltage characteristic (IV) of superconducting contacts has been exploited to obtain the set of transmission coe cients f $_{i}$ g of atom ic-sized alum inum contacts¹⁰. The channel transmission probabilities are extracted by tting the measured IV curve to a sum of N independent IV scalculated for individual channels with a given transm ission probability^{11,12}. This method was afterwards extended to other superconducting m aterials, show ing that the number of conducting channels contributing to the current in one-atom contacts is lim ited by the valence of the atom at the contact².

Gold is not superconducting. However we take advantage of the superconducting correlations induced in a thin layer of norm alm etal in contact with a superconductor. The energy spectrum is modiled and a gap is opened at the Fermi energy. At low voltages transport is dominated by Andreev rejection processes which results in non-linear IV curves. Here we use the aforem entioned m ethod^{2,10} to analyze the transm ission coe cients of proximity induced superconducting one-atom contacts and atom ic chains of gold.

The proximity e ect has been previously exploited^{2,13} to get information of the f ig in gold atom ic contacts. In the rst experiment² the IV curves were tted to a sum of theoretical IV s corresponding to BCS superconductors and the contribution of a single channel in one-atom contacts is reported. However, the energy dependence of the density of states and the probability of Andreev re ection at a proxim ity induced superconducting contact are sm eared with respect to the BCS m del^{15} . The modi cations due to the proxim ity character of the superconducting correlations were taken into account in the later experim ent¹³. Most of the experim ental IV s recorded at the last conductance plateau before contact breaking could be tted with a single channel. Several channels were necessary to t the IV curves of som e contacts with conductance smaller than G_0 . However, in these experiments the conductance of the smallest contacts is usually much smaller than G_0 , being the rst peak of the histogram placed at $0.6 G_0$ and plateaux not nearly at. These results are not consistent with what has been usually reported in gold atom ic contacts in the norm al state¹. Here we report experiments in which the conductance histograms for proximity superconducting gold and norm algold are in remarkable agreem ent (Fig 1). We also study the channel content of chains of gold atom s.

Nanocontacts are produced by pressing two wires crosswise against each other. The wires are used as electrodes in place of tip and sam ple of an STM. The separa-

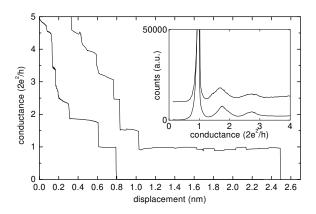


FIG.1: Dierential conductance at a bias voltage of 10 mV of proxim ity induced superconducting gold contact during pullo. One-atom contact form ation (left) and atom ic chain (right). The length of the conductance plateau indicates that a chain longer than ve atom s is form ed. Inset: conductance histogram s of gold in the norm al state (bottom) and proxim - ity superconducting (shifted upwards 10000 counts).

tion and contact size between the wires can be controlled with the piezoelectric positioning system the microscope. The advantage of using two crossed wires is the possibility of selecting the position of the point contact along both wires using the coarse lateral displacem ent capability of the m icroscope, allowing for the exploration of point contacts at di erent spots along the wires. The wires (0.25 mm diameter) are made of bulk lead and are in a rst preparation step covered by therm alevaporation with a thick layer of lead (900 nm at a rate of 0.8 nm/s). This thick layer of lead provides a clean surface. A thin layer of gold (28 nm, rate of 0.1 nm/s) is then evaporated on top of the Pb layer. The lead and gold deposition sequence is perform ed without breaking the vacuum in the chamber (< 10⁶ mbar), thus preventing the presence of oxide at the Pb-Au interface and ensuring good electrical contact between both layers. The substrate is at a tem perature of 80 K during Im deposition. O ne-atom contacts are fabricated by slight indentation (< 3 nm) and subsequent retraction of the electrodes. Further retraction results in contact breaking and a jump to the tunnelling regime. Experiments are done at 1.8 K. During nanocontact pull-o the conductance trace is steplike (see Fig. 1). This characteristic behavior has been shown to be due to the mechanical processes that take place during contact breaking¹⁶; conductance plateaus corresponding to elastic deformation stages and sharp conductance changes related to sudden rearrangem ents of the atom s in the narrowest part of the nanocontact.

For gold nanocontacts in the norm alstate the last conductance plateau before contact breaking is close to G_0 and corresponds to the sm allest possible contact: a oneatom contact. D expite the inherent variability of the ex-

act conductance trace during contact pull-o, it has been shown in several experiments that the conductance histogram (CH) over a large num ber of contact breaking realizations displays peaks at conductance values that are characteristic of the chem ical nature of electrodes¹. CH in gold nanocontacts have a characteristic rst peak at a conductance close to G_0 . We show in the inset of Fig. 1 a comparison between CH obtained for bulk gold tips in the norm al state and in proxim ity induced superconducting gold nanocontacts. Due to the presence of excess current in the IV s of superconducting nanocontacts it is necessary to measure the di erential conductance at a xed bias voltage well above =e, where is the energy of the superconducting gap. The remarkable agreem ent between both CH supports the validity of our analysis also for atom ic-sized contacts of gold in the norm alstate. The low value of the conductance of the rst peak in the conductance histogram in Ref. 13 was probably due to enhanced elastic scattering related to sam ple preparation method.

We show in Fig. 2 representative IV curves recorded at a one-atom contact, in an atom ic chain and in the tunneling regime, up to a voltage 2 $_0$ =e, where $_0$ = 1:40 m eV is the bulk superconducting gap for lead. We show both the measured IV curves (symbols) and theoretical tting (lines). The theoretical IV s in the contact regime are calculated by solving the time-dependent B ogoliubov de G ennesequations within the scattering form alism ^{11,18}. This method requires the know ledge of the Andreev reection am plitude of probability (a (E)) at the contact, where the voltage drops. a (E) can be computed if the norm al and anom alous G reen functions are know n¹⁸. In the tunneling regime the IV s are calculated by the usual convolution of the densities of states at both sides of the barrier¹⁷.

A sboth Au-P b electrodes are only very weakly coupled at the weak link, to calculate the density of states and the Andreev re ection amplitude of probability, we model our system as two independent norm al-superconducting (NS) structures and solve self-consistently the U sadel equations^{14,15}. U sadel equations provide a quasiclassical description of the G reen functions of a superconductor in the dirty lim it, in which electronic transport is di ussive. E lastic impurity scattering is included in the Born approximation and is characterized by a mean free path l (or a di usion coe cient $D = v_F l=3$). A description based on U sadel equations was recently used to explain the IV curves of lead nanostructures under the in uence of a magnetic eld and proximity e ect, providing excellent quantitative agreem ent with experim ent both in the contact and tunneling regim e^{19,20}.

The two NS are assumed to be equal and consist of a dirty norm al layer with thickness d_N which is bounded at one end by vacuum and joined to a dirty sem i-in nite superconductor at the other. Note that the di ussive description is expected to be valid in the case d_N l. The G reen functions which are relevant to calculate the IV curves are the ones at the vacuum -bounded edge of

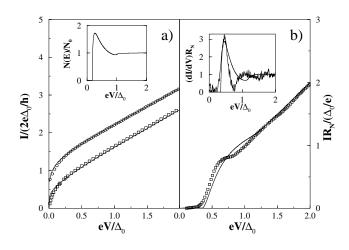


FIG.2: Main gures show the IV curves corresponding to the tunneling regime (b), a single-atom contact (bottom curve in (a)) and an atom ic chain (top curve in (b)). The curve corresponding to the atom ic chain has been displaced for clarity. Experimental results are shown by symbols and theoretical t-tings by solid lines. The transmissions obtained in the contact regime are $T_1 = 0.995$ (single atom), and T = 0.96 (chain). Inset in (a) show s the density of states used to calculate the theoretical curves -see text. Inset in (b) show the derivative of the experimental (the one with noise) and calculated tunneling curves.

the norm al layer. The proxim ity e ect is also, a ected by the existence of a barrier at the interface, as quasiparticles norm ally re ected do not contribute to it. In a di usive system, the mism atch between the characteristic parameters (conductivity and di usion coe cients) of the norm al and superconducting m etals, leads to an effective barrier for the quasiparticles. It can be described through the parameter = $(D_S = D_N)^{1=2} = S$. In our model we assume = 1 and a vanishing resistance of the interface²¹. W ith these assumptions the superconducting correlations in the norm alm etal are described by $_0$ and the value of $d_N = _S$, where $_S$ is the coherence length of the superconductor. In the atom ic chain and one-atom contact the transmission channels set enters also as thing parameters. A similar model was used by Scheer et al^{13} in the description of Au contacts with superconductivity induced by proximity e ect. In their case, how ever, the mism atch parameter was also used as a tting parameter.

Solid lines in Fig. 2 show the calculated IV which for the same sample tting parameter, $d_N = {}_S = 0.81$, best tboth the curves in the tunneling and the contact regime. A ssum ing the nom inal thickness $d_N = 28$ nm it corresponds to a superconducting coherence length ${}_S = 34$ nm, in good agreement with the values obtained in Ref. 19 and 20.

The tunneling regime IV curve, plotted in Fig. 2b, shows a gap smaller than $_0$ and a bump characteristic of NS structures²³. It is how ever poorly tted²⁶, which

m eans that the density of states used, shown in the inset of Fig. 2 (a), does not agree com pletely with the experimentalone. The source of disagreement in the tting can be better understood by looking at the derivative of the experim ental and theoretical tunnel IV curves, shown in inset in Fig. 2 (b). The theoretical curve shows an asymmetric peak at the gap which decays slowly as the energy increases and results from the one in the density of states. This asymmetric peak structure is characteristic of the diusive regime for parameters which give gaps in the norm alm etal much smaller than $_0$. The peak in the experim ental curve is more symmetric. More rounded peaks (and tunneling curves with a bum p m ore sim ilar to the one obtained experimentally) can be obtained form uch sm aller values of $d_N = {}_S$. In the di usive regime the gap induced in the spectrum of the norm al m etal decreases with $d_N = S$. Low er values of the tting parameter induce gaps with values much closer to 0 and could not explain the strong reduction of the gap found experimentally and would give worse ts.

Scheer et al.¹³ also found disagreem ent in the tof the tunneling conductance and related it to the non-di usive character of the samples, being the condition d_N lnot ful lled. The proximity e ect is a consequence of the coherent superposition of Andreev re ection and is strongly in uenced by the length of the path which the electron travels between Andreev re ection processes. Thus, the energy dependence of the induced pair correlations is very sensitive to the degree of disorder in the norm alm etal and the shape of the spectrum di ers considerably in the clean and dirty lim its^{15,22,23}. We have also tried, without success, to t the experim ental curves assuming that there is no disorder being the transport in the electrodes ballistic, instead of di usive^{22,23,24,25}. As concluded by Scheer et al.¹³, we think that the lack of good ttings in the tunneling regime is due to transport in the gold layer being in the weakly disordered regime, instead of in the di usive or clean lim its.

Given the uncertainty in the density of states, the accuracy with which the channel transmission set is obtained in the contact regime is slightly reduced, compared to the ones done in BCS superconductors. The single-atom curve can be reasonably well tted with a very open channel with transmission $T_1 = 0.995$. The chain is reasonably well tted by a single channel with transmission T = 0.96. This result is representative of the general behavior that we observe thus con iming that one widely open channel is responsible for the conduction in single atom gold contacts, in agreement with theoretical predictions^{6,7,8,9}.

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- 26 Slightly better agreement can be obtained with a larger $d_{\rm N}$ = .Larger values of $d_{\rm N}$ = do not t properly the IV curve in the contact regime for any value of the channels transmission..